



## Article

# Crystal Engineering Approach for Fabrication of Inverted Perovskite Solar Cell in Ambient Conditions

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**Abstract:** In this paper, we demonstrate the high potentialities of pristine single-cation and mixed cation/anion perovskite solar cells (PSC) fabricated by sequential method deposition in p-i-n planar architecture (ITO/NiO<sub>x</sub>/Perovskite/PCBM/BCP/Ag) in ambient conditions. We applied the crystal engineering approach for perovskite deposition to control the quality and crystallinity of the light-harvesting film. The formation of a full converted and uniform perovskite absorber layer from porous pre-film on a planar hole transporting layer (HTL) is one of the crucial factors for the fabrication of high-performance PSCs. We show that the in-air sequential deposited MAPbI<sub>3</sub>-based PSCs on planar nickel oxide (NiO<sub>x</sub>) permitted to obtain a Power Conversion Efficiency (PCE) exceeding 14% while the (FA,MA,Cs)Pb(I,Br)<sub>3</sub>-based PSC achieved 15.6%. In this paper we also compared the influence of transporting layers on the cell performance by testing material depositions quantity and thickness (for hole transporting layer), and conditions of deposition processes (for electron transporting layer). Moreover, we optimized second step of perovskite deposition by varying the dipping time of substrates into the MA(I,Br) solution. We have shown that the layer by layer deposition of the NiO<sub>x</sub> is the key point to improve the efficiency for inverted perovskite solar cell out of glove-box using sequential deposition method, increasing the relative efficiency of +26% with respect to reference cells.

**Keywords:** sequential deposition; out of glove-box; layer by layer deposition; NiO<sub>x</sub>; low-cost fabrication



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## 1. Introduction

Organic–inorganic hybrid perovskite cells (PSCs) are a new class of thin film photovoltaic (PV) devices promising to deliver efficient and cost effective solar energy to electricity conversion [1–4]. They are the hot topic in the field, because of their remarkable rise in power conversion efficiency (PCE) up to the current 25.5% record achieved for cell efficiency [5] and beyond 17% PCE of large area perovskite solar modules [6,7] PSC overcame the efficiency of other thin film PV technologies and the next target is matching the performance of crystalline silicon. Their success is certainly attributed to unique optoelectronic and semiconducting properties, which may be adjusted by varying the chemical composition of the material: tunable band gap, [8,9] large absorption coefficient ( $\alpha = 5 \times 10^3 \text{ cm}^{-1}$  at 700 nm) [10],  $\mu\text{m}$ -range carrier diffusion length [11], ambipolar charge carrier transport [12,13], low density of trap states [14], and weak exciton binding energy [15]. Moreover, photoactive layers can be deposited using low-temperature and low-cost solution fabrication techniques, and scalable coating or printing methods allowing Roll-to-Roll (R-2-R) processing for flexible substrates [16–18]. There are many routes

for the deposition and crystallization of the perovskite layers, such as solvent engineering [19–21], crystal engineering [22–24] co-evaporation and sequential evaporation [25–27], vapor-assisted solution process (VASP) [28,29], physical vapour deposition [30,31], and spray deposition [32]. Among them, the two-step perovskite formation or sequential deposition, originally introduced by Liang et al. [33] and then applied to PSCs by Burschka and co-workers [34], permits an easy deposition approach that could be conveniently used for large area devices [35]. In its original formulation for the deposition of  $\text{CH}_3\text{NH}_3\text{PbI}_3$  (MAPbI<sub>3</sub>), the two-step process involves first deposition of  $\text{PbI}_2$  on a substrate and a subsequent dipping in a  $\text{CH}_3\text{NH}_3\text{I}$  (MAI) bath. An optimized two-step deposition produces a high crystallinity of perovskite films (average grain size is more 200 nm), which helps to achieve films with reduced concentration of defects for high efficiency devices [23,24,36,37].

So far, the sequential deposition method was mainly used for n-i-p mesoporous structures and planar [22,24,37], where the perovskite is deposited on an electron transporting layer (ETL) porous scaffold, such as the meso-structured titanium dioxide ( $\text{TiO}_2$ ) and pure thin film of polyoxometalate [38]. This approach permitted to reach very efficient PSCs contributing to the development of the field [23]. However, the direct mesoscopic architecture has a few disadvantages that could compromise its exploitation for industrial applications, such as (i) strong hysteresis effect on the current–voltage (J–V) characteristics [39,40]; (ii) high-temperature process (480 °C) needed to sinter the mesoscopic  $\text{TiO}_2$ ; and (iii) the photocatalytic effects in the titanium dioxide upon ultraviolet (UV) illumination activate degradation processes in the perovskite [41,42]. The presence of hysteresis and the stability issue are also a bottleneck for the planar direct PSC where the mesoporous layer is replaced by a thin ETL such as  $\text{SnO}_2$  [43,44].

In order to eliminate the typical drawbacks of the n-i-p PSC architecture, inverted p-i-n planar structures have been proposed and developed with an increasing effort [45,46]. Here the perovskite is deposited on a hole transporting layer (HTL), which acts as window layer, oppositely to the n-i-p architecture where it is the back contact. The first material used for this application is PEDOT:PSS, a very versatile organic p-semiconductor widely employed in organic photovoltaics [47]. Another polymer, poly(triaryl-amine) (PTAA), has proven to be a reliable material for reproducible high efficiency p-i-n perovskite solar cells [48]. Though efficiency, the liabilities of using organic materials are mostly related to their long time reliability in terms to environmental stability and UV induced degradation [49]. Nickel oxide ( $\text{NiO}_x$ ) is an inorganic stable material with a suitable HOMO level (in the range 5 to 5.6 eV according to the stoichiometry and synthesis) for hole extraction and injection and electron blocking properties in perovskite related applications [50]. Furthermore,  $\text{NiO}_x$  can be deposited from liquid precursor in air [51–53] and annealed at the temperature below 300 °C [54]. Moving to the opposite side of the perovskite active layer, the typical ETL in solution-processed inverted PSCs is a fullerene derivative ( $\text{PC}_{61}\text{BM}$ ) that has the tendency to passivate perovskite surface with a significant suppression of hysteresis and recombination losses [55,56].

Despite the fact, that the sequential deposition of perovskite is well studied and described in the literature for conventional n-i-p structures [23], similar works for inverted planar structures with crystallization of perovskite on a p-type semiconductor surface has been discussed only in few publications and only for the pure MAPbI<sub>3</sub> perovskite [57–59]. The first report of a sequential deposition of perovskite on  $\text{NiO}_x$  on Indium tin oxide (ITO) was in 2014 by Hu et al., whose best optimal device structure with the reactive aluminium back electrode evaporated directly over the Phenyl-C61-butyric acid methyl ester (PCBM) yielded a PCE of 7.6% [58,60]. Even the performance were reported on poly(3,4-ethylenedioxythiophene) polystyrene sulfonate (PEDOT:PSS), where the sequential deposition could not yield performance above 2.6% for a 460 nm thick MAPbI<sub>3</sub> layer, with efficiency dropping with increasing dipping time (hence, perovskite thickness). The authors attribute this to the penetration of 2-propanol (IPA) through  $\text{PbI}_2$ , causing damage to the underlying PEDOT:PSS layer [59]. Recently, J. Duan et al. extended the two-step approach for inverted PSC to a two-cation perovskite FAMAPbI<sub>3</sub> even though the low

final efficiency (10.8%) does not allow to perform a clear assessment of the fabrication methodology.

This work is devoted to filling this gap, a required step considering the high potentialities of the multication perovskite combined with sequential deposition and inverted architecture for industrial exploitation of perovskite photovoltaic technologies. The reasons behind choosing the multication perovskite are its higher reproducibility and superior performance and stability [6,61,62]. The partial substitution of methylammonium with formamidinium helps the stability and the performance of the cells [63], while cesium addition stabilizes the crystal structure of the multication perovskite (single step or sequential deposition). The presence of bromine enlarges the band gap, making the material more versatile in terms of applications [22,64].

As a first step of our work, we have tried to apply the crystal engineering approach for pure MAPbI<sub>3</sub> perovskite deposition following previous work reported in reference [23] and we have optimized the sequential deposition of the MAPbI<sub>3</sub> perovskite layer on NiO<sub>x</sub> HTL reaching 14% efficiency under ambient conditions with relative humidity of 20 to 30%. Other interesting aspect is that the PCBM and BCP (Bathocuproine) layers also were deposited by solution processes, fast and easy method to do while preventing any evaporation step at this stage. We also have compared the deposition of PCBM and BCP inside and outside of glove-box and interestingly there was only a ~9% lost in the efficiency applying PCBM/BCP out of glove-box, the result is presented in Figure S1 and Table S1 in Supporting Materials. In the second part of the work, mixed cation compositions [22] in air for inverted (p-i-n) planar solar cells were optimized. At first, we optimized the Pb(I,Br)<sub>2</sub>/CsI layer deposition by controlling of the pre-heating and sintering procedures to create smooth planar film. The second step included modification of dipping time of substrates into the MAX solution in anhydrous IPA and concentration of multication solution. The efficiency of 15.6% has been achieved, which is superior to previous works presented in the literature. Moreover, during the study, it was revealed that the critical parameters of the technological process are temperature control of the substrate, NiO<sub>x</sub> layer thickness, the multiple layer deposition of NiO<sub>x</sub>, PbX<sub>2</sub> layer and timing for immersed substrates in MA(I,Br) in IPA solution during the second step of the deposition.

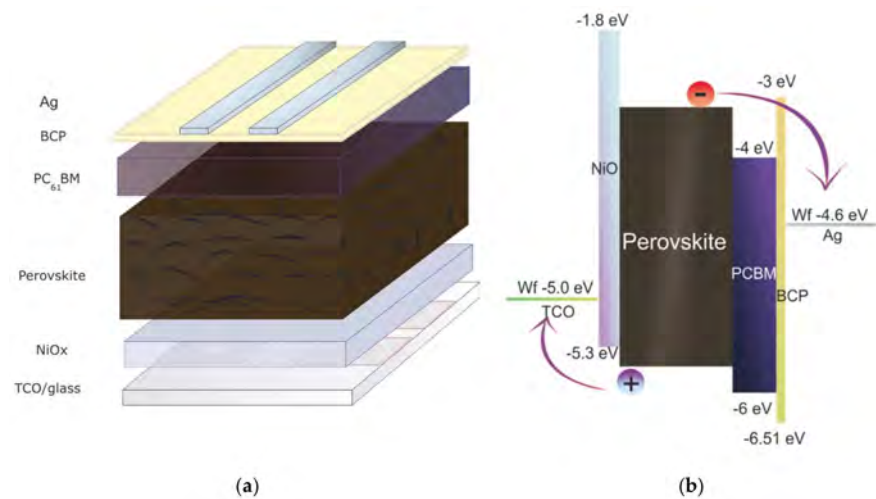
We should point out that PSCs were fabricated with solution processed PCBM and BCP layers from easy and fast approach that prevent the typical evaporation step. Moreover, all J–V measurement of PSCs were obtained in ambient conditions (relative humidity ≈50–60%), under solar simulator with 1 Sun showing hysteresis free plots with high value of current density comparable to meso-structure devices [39].

## 2. Materials and Methods

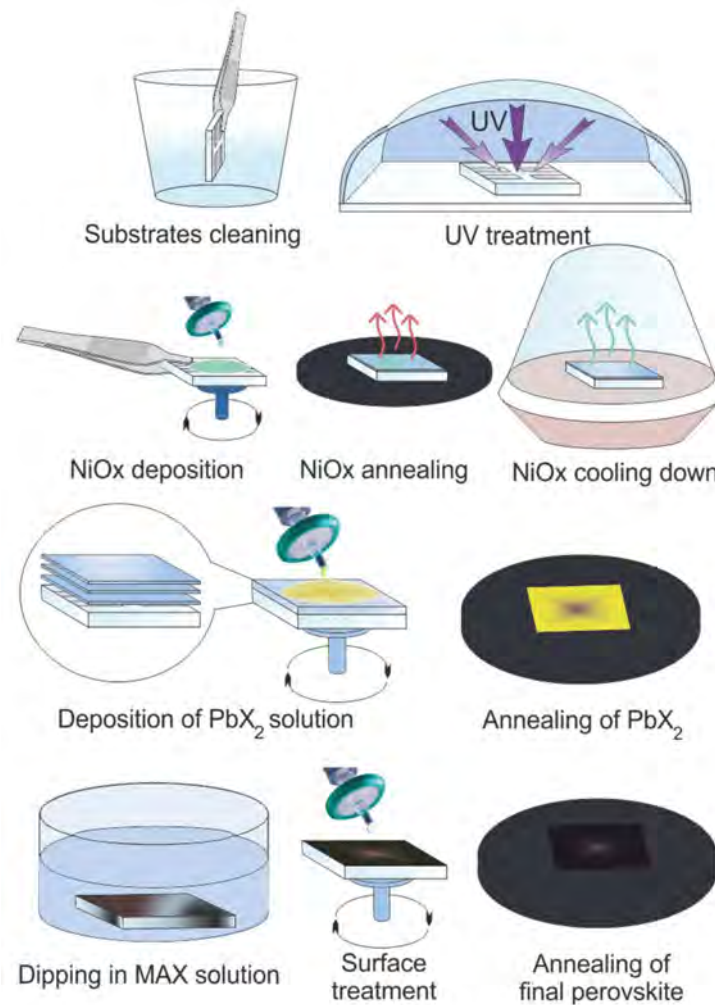
Inverted planar perovskite solar cells have been fabricated considering the glass/TCO/NiO<sub>x</sub>/Perovskite/PCBM/BCP/Ag stack (Figure 1a). Schematic of two-step perovskite formation on NiO<sub>x</sub> HTL is presented in (Figure 2).

### 2.1. Materials

ITO and fluorine doped tin oxide (FTO) substrates were purchased from Kintec and Pilkington, respectively. The solution of NiO<sub>x</sub> was obtained according to a previously reported recipe [53]. The other materials and solvents used are: 2-propanol (IPA, Sigma-Aldrich, anhydrous, 99.5%), lead iodide powder (PbI<sub>2</sub>, TCI, 99.99%), lead bromide powder (PbBr<sub>2</sub>, TCI, 99.99%), methylammonium bromide powder (CH<sub>3</sub>NH<sub>3</sub>Br, Dyesol), formamidinium iodide powder (CH<sub>3</sub>(NH<sub>2</sub>)<sub>2</sub>I, Dyesol), *N,N*-dimethylformamide (DMF, Sigma-Aldrich, anhydrous, 99.8%), cesium iodide (CsI, Puratrem), Dimethyl sulfoxide (DMSO, Sigma-Aldrich, anhydrous, St. Louis, MO, USA, 99.8%), [6,6]-Phenyl C61 butyric acid methyl ester powder (PC<sub>61</sub>BM, Solenne), bathocuproine (BCP, Sigma Aldrich, St. Louis, MO, USA, 99.99%).



**Figure 1.** (a) Schematic representation of p-i-n perovskite solar cells (PSCs); (b) the related energy band diagram of the different functional layers relative to vacuum.



**Figure 2.** Schematic representation of two-step perovskite formation on NiO<sub>x</sub> hole transporting layer (HTL).

### 2.2. Device Fabrication for MAPbI<sub>3</sub> Perovskite

ITO/glass substrates (Kintec,  $15 \Omega \text{ cm}^{-1}$ ,  $25 \text{ mm} \times 25 \text{ mm}$ ) were patterned by a raster scanning laser (Nd:YVO<sub>4</sub> pulsed at 80 kHz) to separate the active area of 4 pixels on each

substrate. Cleaning process of glasses starts with mechanic washing in detergent water (Hellmanex 2% in deionized water) to exclude dusts and visible contaminations. Then substrates were rinsed in deionized (d/i) water, then ultra-sonicated (US) detergent water and then deionized water, acetone, and IPA for 3 min each step, respectively. Surface activation of substrates was carried out under ultraviolet (UV) lamp for 30 min before starting depositions of functional layers. Then, 30 nm NiO<sub>x</sub> hole-transporting layer was deposited on ITO following the procedure described in Ref. [53]: a NiO<sub>x</sub> precursor solution was spin-coated for 50 s at 3000 rpm with 3 s ramp and then annealed at 250 °C for several minutes to evaporate residual solvent. The deposition was repeated for 3 times and then at 300 °C for 60 min on hotplate with closed lid (to minimize influence from environmental fluctuations).

The sequential deposition method was used to fabricate perovskite films on the HTL and the procedure is represented in Figure 2. For the pure MAPbI<sub>3</sub> perovskite following the idea of our previous work [23]. Firstly, 500 mg of PbI<sub>2</sub> was dissolved in DMF while keeping for 20 min at 100 °C to dissolve completely and reaching clear solution and then decreasing the temperature to 70 °C, then 150 µL of solution was deposited on 45 °C NiO<sub>x</sub> substrate (substrate was kept under UV for 30 min and when the temperature reach to 40–45 °C we deposited PbI<sub>2</sub> on the NiO<sub>x</sub> substrate with 5000 rpm for 10 s). PbI<sub>2</sub>-DMF layer was dipped in a solution of methylammonium iodide (CH<sub>3</sub>NH<sub>3</sub>I in anhydrous 2-propanol 10 mg mL<sup>-1</sup>) for 10 min at room temperature while the solution was kept in mechanical stirring during the dipping time. The surface treatment of the film immediately was done with 2-propanol via spin-coating at 6000 rpm with an acceleration rate of 6000 rpm for 10 s. Finally, the devices were annealed at 115 °C for 10 min. All the processes have been done out of glove-box. After that PC<sub>61</sub>BM in chlorobenzene, 20 mg mL<sup>-1</sup> was deposited via spin-coating method a thin layer of ETL was made by 2 sequential steps of spin-coating at 500 rpm—1 s, 1500 rpm—30 s, and annealed at 50 °C for 5 min. Bathocuproine (BCP) in IPA (0.5 mg mL<sup>-1</sup>) was spin-coated as a thin buffer layer between PCBM and the Ag cathode. After electron conductor deposition, solar cells were completed by thermal evaporation (vacuum was 10<sup>-6</sup> Torr) of 100 nm of Ag, which was deposited in an initial slow rate of 0.3 Å/s for the first 10 nm, then 1 Å/s until the final thickness.

The best efficiency reached by this method out of glove-box is 14% which is still higher than the work has been published till now in the literature (maximum PCE of 7.6%).

### 2.3. Device Fabrication for Multication Perovskite

For multication perovskite deposition, firstly, 150 µL of mixed lead solution (Cs-Pb-I-Br) (PbI<sub>2</sub>/PbBr<sub>2</sub>/CsI(1.5 M stock solution of CsI in DMSO)(71:14:15 mol%) in DMF/DMSO (80:20 v%) heated at 70 °C with intensive stirring was dropped on pre-heated at 50 °C substrates and immediately spin-coated in ambient conditions with high relative humidity level (RH) about 50–60%. The solution was dropped by static dispense on the surface and spin-coated 10 s at 4000 rpm. After this procedure to improve material adhesion over the full surface and achieve porous layers, the substrates were sequentially heated at 40 °C for 2 min, then were dried in desiccator for 3 min. The second step consists of the dipping of the cooled-to-room-temperature layers in multication solution of FAI/MABr (88:12 mol%) in anhydrous 2-propanol with concentrations of 40 mM for 10, 20, 25, 30, 35, and 45 min to completely convert lead films into perovskite. In this dipping time the films turn from yellow color to dark brown/black. The best performance perovskite reaches by 30 min dipping in MAX solution. The final steps are surface treatment of the perovskite film with anhydrous 2-propanol pure solvent which deposited by spin-coating at 6000 rpm for 10 s and final annealing at 115 °C for 10 min. The full detailed procedure and method is reported in Ref. [23]. After perovskite full formation in air, the organic electron-transporting layer and a thin buffer layer and electron conductor were deposited as, mentioned above for MAPbI<sub>3</sub>. After metal cathode deposition by thermal evaporation, samples were removed from the vacuum chamber to dry in ambient conditions for oxygen saturation of samples for the next 4 h. It was noted that samples which were measured

immediately showed lower performance than devices left settling in air. The picture of different layers is presented in the Supporting Materials Figures S2 and S3.

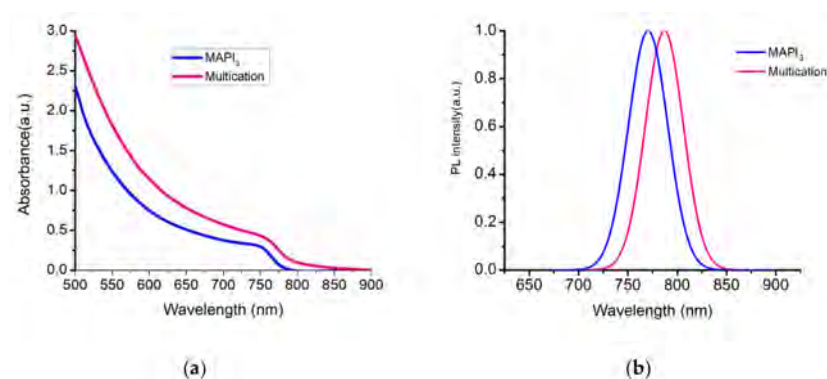
#### 2.4. Device Measurement and Evaluation

Fabricated perovskite solar cells were measured using a solar simulator ABET Sun 2000, class A calibrated with certified Si cell and Ophir irradiance meter under AM 1.5 G and  $100 \text{ mW}\cdot\text{cm}^{-2}$  of illumination conditions in air with active area equals  $0.16 \text{ cm}^2$ . Scan of J-V-parameters of devices were measured in both reverse (open-circuit voltage (Voc) to 0) and forward (0 to Voc) scan directions with 0.1 V step via a Keithley 2400 SMU controlled by a home-made Labview software. External quantum efficiency (EQE) EQE is based on a 300 W Xenon lamp and double grating (300 to 1400 nm). A correct integration of the incident monochromatic light was made by comparison with a photo-response of a Si UV-enhanced NIST calibrated photodetector, transient photocurrent (TPC) and Transient Photo Voltage (TPV) analysis of devices was performed with an ARKEO system from Cicci Research. In the TPV tests a high-speed LED based system (5000 Kelvin) is used to create small perturbation optical signals tuned to maintain voltage deflection within 50 mV. Steady state light was increased from 0.3 to 2 SUN equivalent Optical characterizations of films were executed with BLACK-Comet UV-VIS Spectrometer and ARKEO system. Morphological characterization of perovskite films was made with Profilometer and Scanning Electron Microscopy ZEISS. For the PL test the substrate is by a diode-pumped solid-state (DPSS) Nd:YVO<sub>4</sub> + KTP Laser (Peak wavelength  $532 \text{ nm} \pm 1 \text{ nm}$ , Optical power 1 mW) at an inclination of 45° creating a circular spot 2 mm in diameter ( $31 \text{ mW}/\text{cm}^2$ ) or with a collimated UV LED (Peak wavelength  $380 \text{ nm} \pm 5 \text{ nm}$ )

### 3. Results and Discussion

#### 3.1. Absorbance + Photoluminescence (PL)

Absorbance spectra were measured on mixed cation/anion Cs-CH<sub>3</sub>NH<sub>3</sub>-CH<sub>3</sub>(NH<sub>2</sub>)<sub>2</sub>-Pb(I-Br)<sub>3</sub> (here called multication) and pure MAPbI<sub>3</sub> perovskite films fabricated by two-step method of fabrication inverted perovskite solar cells in ambient conditions. Figure 3a shows the UV-VIS absorption spectra of multication and pure MAPbI<sub>3</sub> films. The absorbance spectrum of the multication shows an onset at 760 nm which is representing ~10 nm red shift with higher intensity compare to MAPbI<sub>3</sub> absorbance spectrum. To prove the obtained current value, we measured absorbance for each multication perovskite films depending on dipping time (shown in Figure S4a). The PL measurements were performed on perovskite films with (multication or MAPbI<sub>3</sub>)/NiO<sub>x</sub>/FTO configuration. Figure 3b shows the normalized PL spectrum of both films. The PL peaks of the films for pure MAPbI<sub>3</sub> and multication point at 764.2 nm and 782.5 nm, respectively. This confirms the different band-gaps of the two compositions, with MAPbI<sub>3</sub> having a 1.56 eV energy gap and multication perovskite with a 1.63 eV band gap, as reported in the literature [22,64,65].



**Figure 3.** (a) Absorbance spectra for multication and MAPbI<sub>3</sub> perovskite films; (b) Photoluminescence (PL) of multication and MAPbI<sub>3</sub> films on NiO<sub>x</sub>/FTO.

The PL measurements of multication perovskite films with different dipping time is reported in Figure S4b.

### 3.2. Subsection Perovskite Film Formation and Dipping Time

In order to achieve a higher efficiency of solar devices than previous reports [58], firstly, multication perovskite deposition has to be optimized by varying the dipping time for better coverage of the surface and, most of all, to increase the thickness of the absorber. We started to immerse our samples in mixed FA-MA cation solution for mixed cation/anion perovskite formation from 10 min and increased this time at 5 min-steps, reaching to 45 min. As a result, we measured dependence of short-circuit current density ( $J_{SC}$ ) and efficiency (PCE) on dipping time on one-layer NiO<sub>x</sub> that correspond to a thickness of around 8–10 nm. Statistic PV parameters were extracted from J–V plots and are presented in Figure S5b–e. As shown in Figure S5a,  $J_{SC}$  increases until 30 min dip-coating and then decreases for longer dipping times.

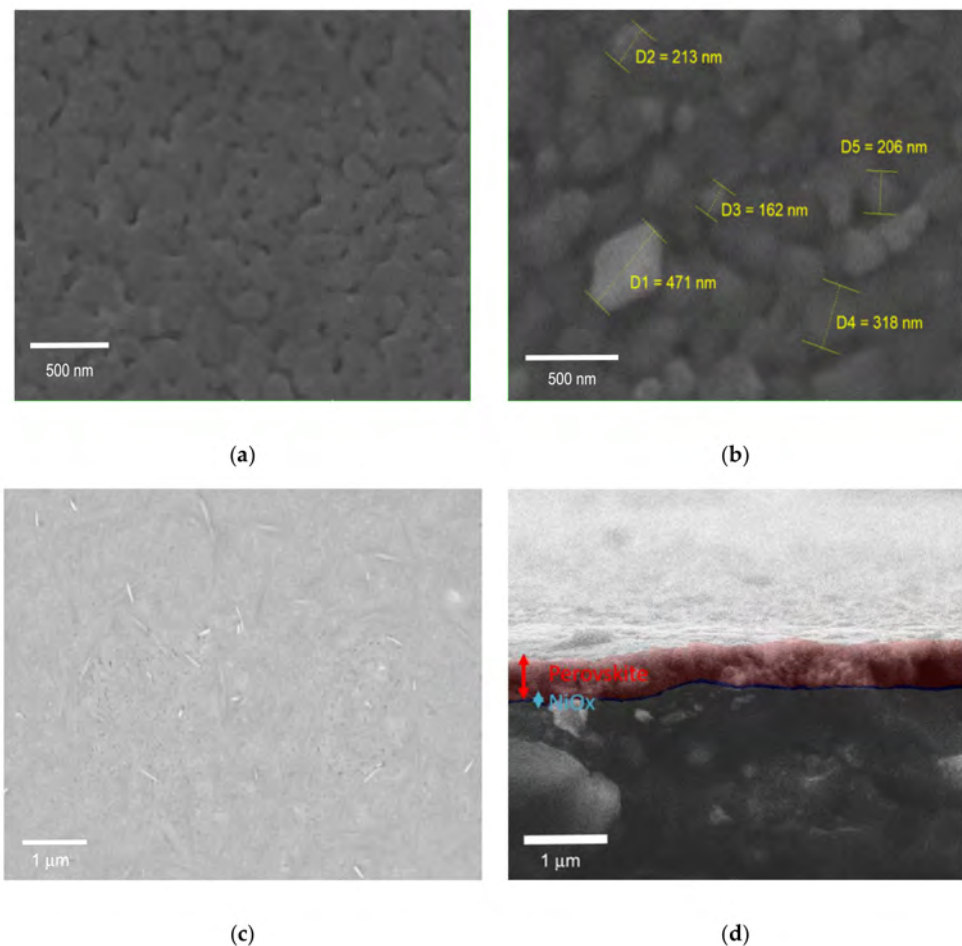
Using a two-step method for inverted planar structure we achieved a higher  $J_{SC}$  with respect to a single-step coating [66]. The single-step spin-coating method has a morphological limitation (lower grain size and reduced absorber thickness), while applying the two-step sequential technique leads to a more controlled crystallization of the perovskite film. The dependence of  $J_{SC}$  on the dipping time could be explain this by two concurring causes. As the thickness increases (increasing dipping time), the charge carriers which are photo-generated away from the extraction layers will have to travel through a longer distance. If this distance is longer than the diffusion length, non-radiative recombination phenomena becomes important. This is also witnessed by the reduction of the open-circuit voltage ( $V_{OC}$ ) for dipping time longer than 30 min. At the same time, even though a thicker perovskite layer should result in improved light harvesting, the lower amount of collected charge carriers will result in a reduction  $J_{SC}$  as observed for long dipping time. In addition, after an initial time in which most of the lead halide film is converted to perovskite, the IPA in the solvent starts dissolving the film and prolonged dipping time could result in a damage of the perovskite layer. As a result, efficiency drops, following the same trend of the current density.

Since amelioration of the perovskite film quality is one of the key parameters for highly efficient PSCs, we evaluated the effects of the annealing environment on initial PbX<sub>2</sub>/CsI film. Firstly, we attempted to get rid of the cloudy surface of the obtained film. Compared to 2 kinds of annealed on 40 °C and 50 °C lead iodide-bromide films, we found that on planar n-i-p structure less annealing temperature (40 °C) of PbX<sub>2</sub>/CsI layer leads to formation of pin hole-free, large crystals and clean-bright surface which is generally more suitable. Moreover, excess amount of PbX<sub>2</sub> layer which is remained on the interface HTL/Perovskite has a positive effect deriving from the passivation of defects (at the interface and grain boundary), thus minimizing energy losses [67]. In addition, dip-coating of cold substrates in mixed cation solution promotes the fast growth of perovskite crystals by penetration of mixed cations through the PbX<sub>2</sub>/CsI layer. The nucleation process directly depends on dipping time, concentration of the solution, relative humidity and surface coverage. Larger perovskite crystals formation leads to high values of current density. The photocurrent density increases up to around 22 mA/cm<sup>2</sup> confirming larger perovskite grains [68]. Wanyi Nie and co-workers explained that high value of PSC performance is due to an increased mobility and lower bulk defects (lower trap state density and reduced recombination centres) in large-size perovskite grains [69]. It meant that (i) micro-scale perovskite grains have low bulk defects and higher mobility of carriers, allowing for the unhampered migration and collection of charges; (ii) the reduced interfacial area associated with large grains suppresses charge trapping and eliminates hysteresis (irrespective of the direction of voltage sweep or the scan rate) [69].

In this respect, the lower Fill Factor (FF) exhibited by our devices is related more to the perovskite/NiO<sub>x</sub> interface, which will need to be optimized by surface modifications

or doping of the hole selective layer to reduce the non-radiative recombination happening at that interface [56,70].

The above consideration on grain size is also supported by the morphological investigation of our sample performed via Scanning Electron Microscopy (SEM). Figure 4a,b shows the SEM image of  $\text{PbI}_2$  layer and  $\text{MAPbI}_3$  films, the  $\text{PbI}_2$  film appears to be smooth, but porous at the same time. The porosity of the spin-coated lead halide layer is conserved by the low temperature annealing ramp [23], in a similar manner to what happens for the fabrication of other porous films like in the mesoscopic perovskite solar cell structure. As it is shown in the Figure 4b the size of  $\text{MAPbI}_3$  grain is around 200 to 450 nm. Figure 4c shows the SEM image of  $\text{FTO}/\text{NiO}_x/\text{PbI}_2\text{-PbBr}_2\text{-CsI}$  films after the first step of the CE method needed to prepare lead contained film. Figure 4d shows the SEM image of  $\text{Glass-FTO}/\text{NiO}_x/\text{multication perovskite}$  film reaching around 500–550 nm thickness of perovskite layer. To confirm the obtained thickness results for perovskite layer and allow a direct comparison of the different absorber films and the corresponding dipping times, we measured by profilometry both kinds of perovskite compositions. Increasing the dipping time for both cases leads to the perovskite thickness rise.



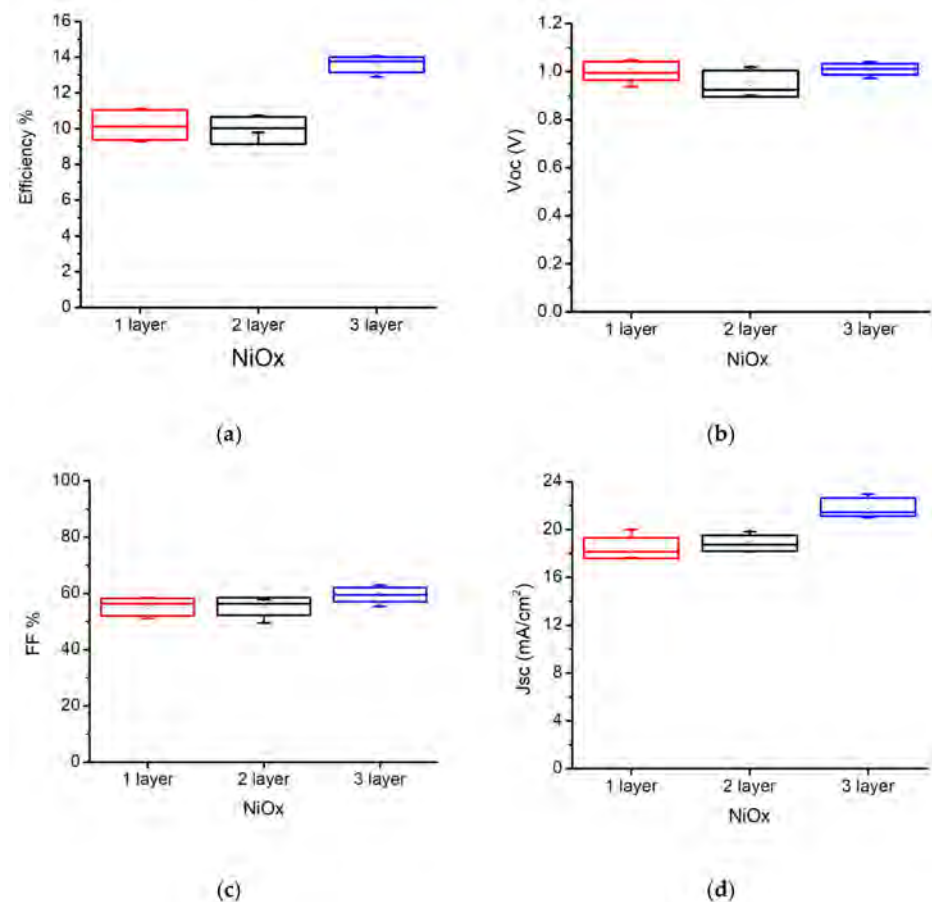
**Figure 4.** (a) Scanning Electron Microscopy (SEM) image of the  $\text{PbI}_2$  film; (b)  $\text{MAPbI}_3$  perovskite film; (c)  $\text{Pb}(\text{Br-I})_2$  film surface on  $\text{NiO}_x/\text{FTO}$ ; (d) Cross-section of multication perovskite film on  $\text{NiO}_x/\text{FTO}$ .

### 3.3. Photovoltaic Performance

The statistic photovoltaic parameters of  $\text{MAPbI}_3$  on multiple layer  $\text{NiO}_x$  and relation to the efficiency is presented in Figure 5 and Table 1. The results show that by increasing the thickness of  $\text{NiO}_x$  through layer-by-layer deposition, Fill Factor and  $J_{\text{SC}}$  and efficiency has been improved. Accordingly, we selected the three-layer deposited  $\text{NiO}_x$  (~30 nm thickness)



for all perovskite structures. Furthermore, photovoltaic parameters of best fabricated MAPbI<sub>3</sub> and multication PSCs under 1 Sun (AM 1.5 G irradiance of 100 mW/cm<sup>2</sup>) are presented in Table 2, where the maximum efficiency for the champion multication PSC is higher than the best MAPbI<sub>3</sub> PSC. A PCE of 15.63% ( $J_{SC} = 21.92 \text{ mA/cm}^2$ ,  $V_{OC} = 1.04 \text{ V}$ ,  $FF = 68.75\%$ ) and 14% ( $J_{SC} = 22.5 \text{ mA/cm}^2$ , a  $V_{OC} = 1.00 \text{ V}$ , and  $FF = 62.5\%$ ) were achieved for multication and MAPbI<sub>3</sub> perovskite, respectively while all the deposition of the NiO<sub>x</sub> and perovskite layers and measurements were performed under ambient air conditions (out of glove-box). J–V curves of the champion multication and MAPbI<sub>3</sub> PSCs are presented in Figure S6. On the other hand, we also tested the fully out of glove-box deposition (including the PCBM/BCP deposition) and the results just showed ~9% decay of the performance respect to inside glove-box deposition of PCBM/BCP layer (Figure S1 and Table S1).



**Figure 5.** Statistical photovoltaic parameters of the of MAPbI<sub>3</sub> perovskite vs. multiple NiO<sub>x</sub> layer deposited: (a) Power Conversion Efficiency (PCE); (b) open-circuit voltage ( $V_{OC}$ ); (c) Fill Factor (FF); (d) short-circuit current density ( $J_{SC}$ ).

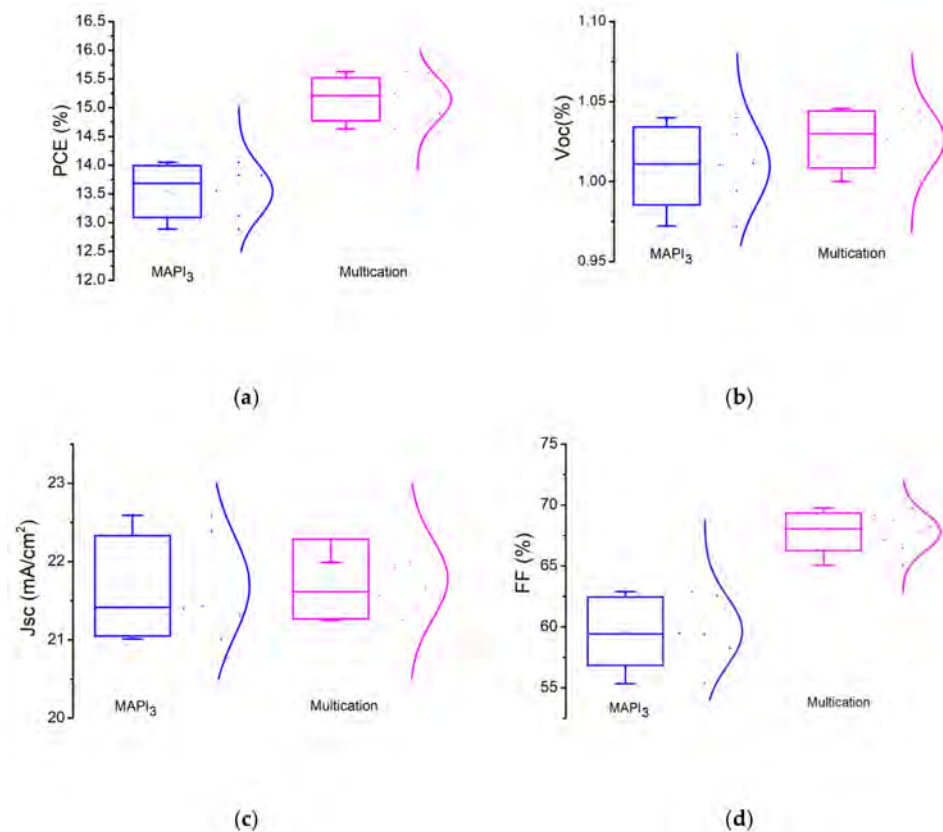
**Table 1.** The best (average) photovoltaic parameters of the of MAPbI<sub>3</sub> based PSCs for different layers of NiO<sub>x</sub>.

File Name	$V_{OC}$ (V)	$J_{SC}$ (mA/cm <sup>2</sup> )	FF (%)	PCE (%) Best (Average)
MAPbI <sub>3</sub> (1 NiO <sub>x</sub> layer)	1.04 (1.027 ± 0.027)	18.22 (18.07 ± 0.28)	58.21 (57.53 ± 1.01)	11.1 (10.82 ± 0.47)
MAPbI <sub>3</sub> (2 NiO <sub>x</sub> layer)	1.02 (0.96 ± 0.06)	18.24 (18.17 ± 0.29)	57.75 (56.50 ± 1.39)	10.74 (10.18 ± 0.36)
MAPbI <sub>3</sub> (3 NiO <sub>x</sub> layer)	1.00 (1.01 ± 0.02)	22.59 (21.87 ± 0.70)	62.53 (59.61 ± 2.37)	14.05 (13.57 ± 0.39)

**Table 2.** The best (average) photovoltaic parameters of optimized PSCs.

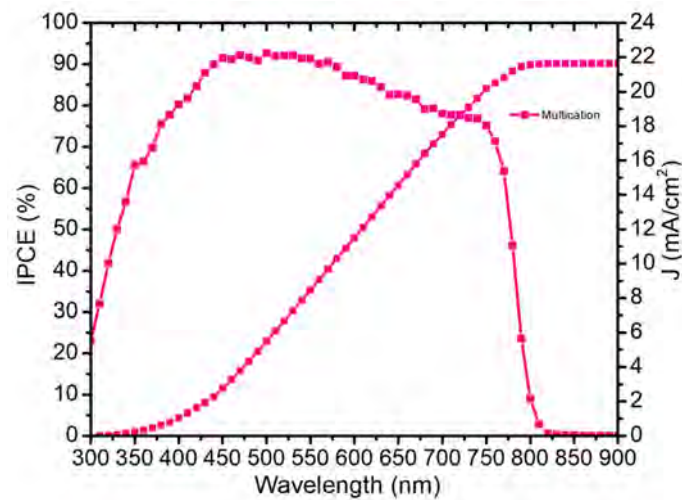
File Name	V <sub>OC</sub> (V)	J <sub>SC</sub> (mA/cm <sup>2</sup> )	FF (%)	PCE (%) Best (Average)
Multication perovskite	1.04 (1.03 ± 0.02)	21.92 (21.78 ± 0.51)	68.75 (67.80 ± 1.53)	15.63 (15.15 ± 0.37)
MAPbI <sub>3</sub>	1 (1.01 ± 0.02)	22.59 (21.70 ± 0.64)	62.53 (59.65 ± 2.80)	14.05 (13.54 ± 0.45)

Statistic PV parameters of the multication and MAPbI<sub>3</sub> PSCs are also presented in Figure 6. The comparison shows higher PCE values for multication PSCs vs. MAPbI<sub>3</sub> devices which mainly attributed to enhancement of FF. Such improvement of the FF would be attributed to better perovskite/NiO<sub>x</sub> interface. Under 1 Sun, the V<sub>OC</sub> observed ranges from 1 to 1.05 V for multication perovskite, whereas for MAPbI<sub>3</sub> it is 0.97 to 1.04 V. Table 2 illustrates the statistics of the main output parameters of perovskite devices with inverted planar structure.

**Figure 6.** Statistical photovoltaic parameters of the of MAPbI<sub>3</sub> perovskite vs. multication perovskite: (a) PCE; (b) V<sub>OC</sub>; (c) J<sub>SC</sub>; (d) Fill Factor.

The inverted planar PSCs based on sequential deposition of multication perovskite absorber with 30 min dipping time exhibits a 15.6% PCE. This is currently a valuable PCE for two-step deposited p-i-n PSCs with NiO<sub>x</sub> hole selective layer, in which the absorber is made in ambient conditions (relative humidity—50–60%).

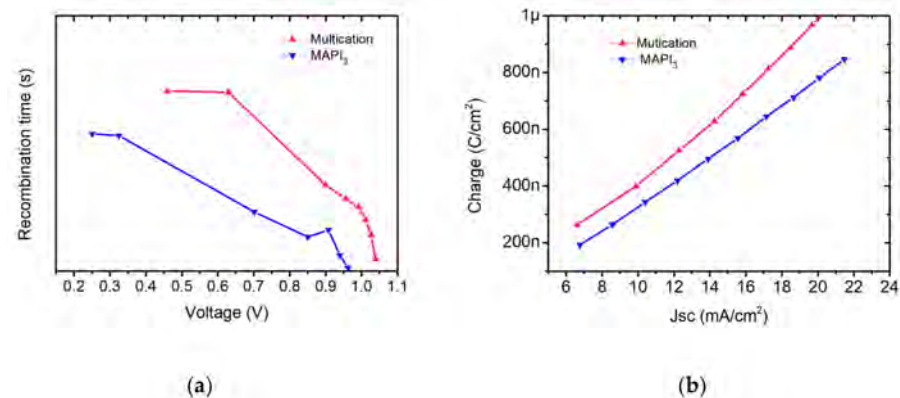
This max value of the J<sub>SC</sub> is also confirmed by the External quantum efficiency (EQE) spectrum of as presented in Figure 7. The integrated J<sub>SC</sub> of multication perovskite was calculated to be 21.628 mA/cm<sup>2</sup>, which is within a reasonable range from the J–V measurements at 1 Sun.



**Figure 7.** EQE measurement of the best multication solar cells fabricated by two-step deposition.

### 3.4. Transient Photovoltage (TPV) and Transient Photocurrent (TPC)

To study the charge extraction and recombination statistics, the methods of transient photovoltage (TPV) under open circuit ( $V_{OC}$ ) condition and charge carrier extraction (CE) were applied to our cells. The TPV is based on identifying the charge carrier lifetime upon monitoring the photovoltage decay. In Figure 8a multication PSC showed higher recombination time (longer lifetime) than  $\text{MAPbI}_3$  PSC justifying the J–V-measurements. This is explained by a better film quality in multication perovskites, which leads to reduced recombination within the films and longer diffusion lengths and recombination times. This is also evident because the  $V_{OC}$  and FF of multication perovskite is higher than  $\text{MAPbI}_3$  [22,64]. Jia-Shang Zhao et al. explained that in mixed-cation, mixed-halide perovskite the carrier recombination process occurs with distinct processes (biphasic trap assisted carrier recombination mechanism) in the device: the two perovskite phases coexisting in the film dominate at different potentials, with the methylammonium lead iodide phase showing the fastest recombination dynamics [71].



**Figure 8.** (a) Recombination time versus voltage, evaluated from transient photovoltage decay analysis of the PSCs. (b) Charge extraction curves of the PSCs obtained from transient photocurrent fall/rise analysis.

Charge carrier kinetics in perovskite cells were identified by transient photocurrent (TPC) method under solar relevant conditions. The extracted charges from the photocurrent decay for each kind of perovskite are plotted in Figure 8b. It is evident that charge extraction is better in the optimized multication perovskite compared to  $\text{MAPbI}_3$ , confirming the important role of charge extraction in the photovoltaic performances (Figure 6).

#### 4. Conclusions

In conclusion, in this paper we showed for the first time a sequential deposition for multication perovskite out of glove-box on inverted structure p-i-n perovskite solar cells with nickel oxide hole transporting layer. We adapted the crystal engineering approach to fabricate inverted perovskite solar cells in ambient conditions in order to achieve high quality perovskite films with large grain size. We showed that the dipping time and annealing for the second step of the deposition process is a crucial element that helps getting large grains and therefore higher short-circuit current densities. The optimized procedure, consisting in a 30 min dipping time for multication perovskite, yields a champion device with power conversion efficiency of 15.6%. The sequential deposited MAPbI<sub>3</sub> perovskite solar cells on planar NiO<sub>x</sub> (HTL) reached exceeding 14%. The comparison with the reference, methylammonium lead triiodide perovskite, shows that multication PSCs have improved performance, confirmed by charge extraction and carrier lifetime measurements. Multiple layer NiO<sub>x</sub> is crucial parameter to get better FF, J<sub>sc</sub>, and efficiency. We have proved that for sequential deposition we need the thicker NiO<sub>x</sub> layer. However, the FF of the cells still need further improvement, which will be addressed in future developments. This work could pave the way for high efficiency large area out of the glove-box fully solution-processed, low cost fabrication perovskite solar devices.

**Supplementary Materials:** The following are available online at <https://www.mdpi.com/1996-1073/14/6/1751/s1>, Figure S1: Statistical photovoltaic parameters of the of MAPbI<sub>3</sub> perovskite applying PCBM and BCP outside and inside glove-box: (a)—PCE, (b)—J<sub>SC</sub> (c)—Fill Factor, and (d)—V<sub>OC</sub>, Table S1: The best parameters and average values of MAPbI<sub>3</sub> perovskite applying PCBM and BCP outside and inside glove-box: (a)—PCE, (b)—J<sub>SC</sub> (c)—Fill Factor, and (d)—V<sub>OC</sub>, Figure S2a—Absorbance of multication perovskite films (different dipping time), Figure S2b—PL of multication films on NiO<sub>x</sub>/FTO (different dipping time), Figure S3—(a) Multication perovskite: J<sub>sc</sub> dependence on dipping time in multication solution; (b–e)—Electrical parameter statistics for the investigated multication perovskite-based device acquired at 1 Sun irradiation. The cell active area is 0.16 cm<sup>2</sup>. Figure S4—J–V-plots of two-step (a)—Multication and (b)—pure MAPbI<sub>3</sub> perovskite solar cells, Figure S5—Pb and PbX<sub>2</sub> layer, perovskite layers.

**Author Contributions:** I.E. wrote the original draft of the manuscript; I.E. and N.Y.N. performed the experiments and measurements; I.E. and N.Y.N. analyzed and extracted the data; I.E., N.Y.N., E.L. and A.D.C. wrote, reviewed, and edited the final draft; I.E. prepared samples for SEM measurement; E.D.B. and E.K. performed the SEM measurement; L.L. synthesized the NiO<sub>x</sub>; A.D.C. and N.Y.N. conceived the idea; N.Y.N. and A.D.C. supervised the work; A.D.C. project administration and funded acquisition. All authors have read and agreed to the published version of the manuscript.

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